



BC546TAR Information



For Reference Only

Part Number BC546TAR

Manufacturer Fairchild/ON Semiconductor

Category Discrete Semiconductor Products
Transistors - Bipolar (BJT) - Single

Description TRANS NPN 65V 0.1A TO-92

Package TO-226-3, TO-92-3 (TO-226AA) (Formed Leads)

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



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BC546TAR Specifications

Manufacturer Part NumberBC546TARManufacturerFairchild/ON SemiconductorCategoryDiscrete Semiconductor ProductsTransistors - Bipolar (BJT) - SinglePackageTO-226-3, TO-92-3 (TO-226AA) (Formed Leads)Series-Transistor TypeNPNCurrent - Collector (Ic) (Max)100mAVoltage - Collector Emitter Breakdown (Max)65VVce Saturation (Max) @ Ib, Ic600mV @ 5mA, 100mACurrent - Collector Cutoff (Max)15nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce110 @ 2mA, 5VPower - Max500mWFrequency - Transition300MHzOperating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA) (Formed Leads)	Des-10111K Specifications	
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Current - Collector (Ic) (Max) Voltage - Collector Emitter Breakdown (Max) Vce Saturation (Max) @ Ib, Ic 600mV @ 5mA, 100mA Current - Collector Cutoff (Max) DC Current Gain (hFE) (Min) @ Ic, Vce 110 @ 2mA, 5V Power - Max 500mW Frequency - Transition 300MHz Operating Temperature 150°C (TJ) Mounting Type Through Hole Package / Case TO-226-3, TO-92-3 (TO-226AA) (Formed Leads)	Series	-
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Power - Max 500mW Frequency - Transition 300MHz Operating Temperature 150°C (TJ) Mounting Type Through Hole Package / Case TO-226-3, TO-92-3 (TO-226AA) (Formed Leads)	Current - Collector Cutoff (Max)	15nA (ICBO)
Frequency - Transition 300MHz Operating Temperature 150°C (TJ) Mounting Type Through Hole Package / Case TO-226-3, TO-92-3 (TO-226AA) (Formed Leads)	DC Current Gain (hFE) (Min) @ Ic, Vce	110 @ 2mA, 5V
Operating Temperature 150°C (TJ) Mounting Type Through Hole Package / Case TO-226-3, TO-92-3 (TO-226AA) (Formed Leads)	Power - Max	500mW
Mounting Type Through Hole Package / Case TO-226-3, TO-92-3 (TO-226AA) (Formed Leads)	Frequency - Transition	300MHz
Package / Case TO-226-3, TO-92-3 (TO-226AA) (Formed Leads)	Operating Temperature	150°C (TJ)
	Mounting Type	Through Hole
	Package / Case	TO-226-3, TO-92-3 (TO-226AA) (Formed Leads)
Supplier Device Package TO-92-3	Supplier Device Package	TO-92-3
Report errors?		Report errors?

BC546TAR Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

BC546TAR Payment Methods





















BC546TAR Shipping Methods













If you have any question about BC546TAR, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com